

Notice of References Cited	Application/Control No. 09/916,701	Applicant(s)/Patent Under Reexam Ooi et al	
	Examiner Savitri Mulpuri	Art Unit 2812	Page 1 of 1

U.S. PATENT DOCUMENTS

	Document Number Country Code-Number-Kind Code	Date MM-YYYY ¹	Name	Classification ²	
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B	4,871,690	10/1989	Holonaya et al	438	46
C	20,020,127,752	9/2002	Thomson et al	438	22
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NON-PATENT DOCUMENTS

	Include, as applicable: Author, Title, Date, Publisher, Edition or Volume, Pertinent Pages
U	Lam et al "Plasam immesrsion Ar ions ion implantation induced disorder in strained InGaAsP multiple quantum wells" Electronic letters, April 1998 vol. 34 no. 8
V	Poole et al "Bandgap tuning of semiconductor quantum well structures using ion implantation", Sperlattices and Mircrostructures vol. 15, no. 4 1994
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* A copy of this reference is not being furnished with this Office action. See MPEP § 707.05(a).

¹ Dates in MM-YYYY format are publication dates.

² Classifications may be U.S. or foreign.